



CHARACTERISATION OF MANGANESE DOPED CDO THIN FILMS PREPARED BY DIP COATING METHOD

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ABSTRACT

Transparent and conducting cadmium oxide (CdO) and manganese doped cdo (Mn:CdO) thin films were deposited using a low cost dip coating method on the glass substrate at 400°C. For Mn doping concentration of manganese chloride 2% (0.039582gm) was used in the spraying precursor solution. The CdO and Mn film were investigated using uv-vis spectroscopy, FTIR spectroscopy and thickness measurement. The optical band gap of the films decreases from 5.69 eV with increasing concentration of manganese, Optical absorption spectra of Cdo film decreases with increases doping concentration of manganese. The FTIR study reveals that the CdO and Mn the functional groups are presented. The Air wedge method of CdO and Mn: the thickness of the thin films to increases with CdO doping percentage from pure CdO 1.2504×10^{-3} mm at 0.1% Mn 4.1344×10^{-3} mm. It is observed that the Mn doped CdO is higher than the pure CdO.

KEYWORDS: Cadmium Oxide, Dip Coating, UV, FTIR, Air Wedge

INTRODUCTION

Transparent and conducting in the form of thin films has been used in applications such as photodiodes, phototransistors, photovoltaic cells, transparent electrodes, liquid crystal displays, IR detectors, and anti reflection coatings. CdO micro particles undergo band gap excitation when exposed to UV-A light and is also selective in phenol photo degradation.

This application of the material is used to cadmium plating baths, electrodes for storage batteries, cadmium salts, and catalyst. It is also available in pellets, pieces, powder, sputtering targets, tablets, and nanopowder. Cadmium oxide (CdO) is an inorganic compound; It has crystallizes in a cubic rock salt at different temperatures. Their various fabrication techniques, the dip coating is mostly used method of preparing transparent oxide thin films.

The hope of this preparation is to find, the evaluate of the layer on the surface bonding and Air wedge method is used to calculated the thickness of the coating film is compared to ordinary film.

Scope of the work:

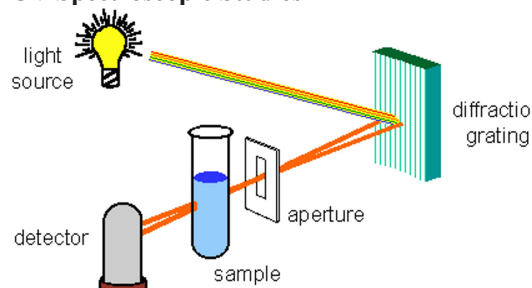
In the present work, Cadmium oxide (CdO) thin films were prepared on glass substrates by sol-gel dip coating technique. In a beaker, 0.1M of cadmium oxide was dissolved in 50 ml of deionized water. The solution was continuously stirred by a magnetic stirrer for 1 hour to get a clear homogeneous solution. Then 2% (0.039582gm)

of manganese chloride is added and stirred few seconds then Ammonium hydroxide (NH₃. H₂O) solution was added drop wise till the pH is reached 12. The Mn doped CdO thin film was prepared.

This solution is taken in small beakers and the glass substrates were dipped into beakers for 24 hours. The glass slides were dried in room temperature. These slides are annealed at 400°C and used for the characterization techniques. The annealed films were studied for their surface bonding and thickness Properties.

RESULT AND DISCUSSION

UV Spectroscopic Studies



The absorption spectra in the wavelength region of 100nm- 600nm for the Mn. CdO of different concentration (0.1M) deposited on glass substrates at annealing temperature 400°C were studied. It is observed that the absorbance increases with doping concentration of precursor solution. The absorbance spectrum of Mn doped CdO thin films are shown in fig. It is clear that as the concentration increases, the absorbance of

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the film is also increase. The band gap energy value for the Mn. CdO was further increased.

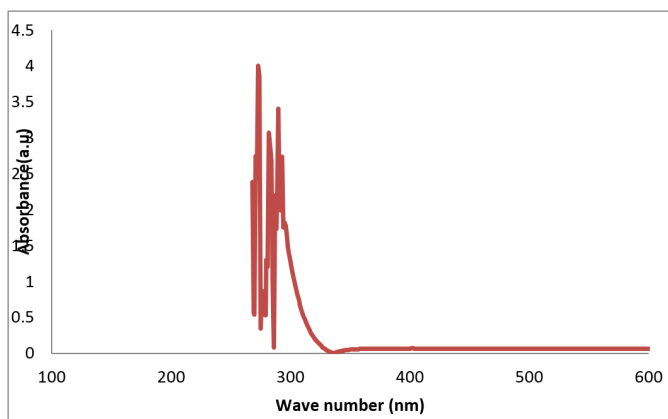


Figure 1: U V Spectrum of Mn. CdO thin films

The band gap is calculated using the formula is given by,

$$E_g = \frac{hc}{\lambda} \text{ eV}$$

Where, h is the Planck's constant $h=6.626 \times 10^{-34} \text{ m/s}$ and c is the velocity of light $c=3 \times 10^8 \text{ m/s}$, λ is the calculated wavelength of the Spectrum in eV.

The wavelength and band gap energy is compared with pure cadmium oxide and manganese doped cadmium oxide. As the concentration percentage is increased band gap energy is increased.

Material	Wavelength (λ) nm	Band gap(E_g)
Pure CdO	340	3.65 eV
Mn.cdo	320	3.88 eV

The Ultra – Violet visible spectroscopy studies show that the Mn doped band gap energy 3.88 eV. The few amount of doping concentration the band gap energy is decreased.

FTIR Spectral studies

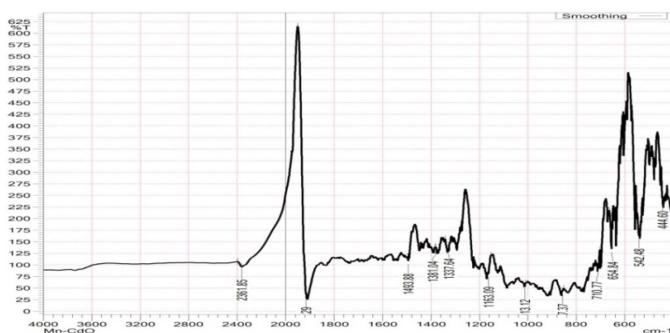


Figure 2: FTIR Spectrum of Mn. CdO thin films

FTIR Spectrum of Mn doped CdO thin films

Figure 2 shows the Fourier Infrared Spectroscopy of the Mn doped CdO films. The obtained FTIR spectrum of Mn doping CdO thin film with p^H 12 and annealing temperature at 400°C is shown in fig. The absorption peak at 1916.29 cm^{-1} is assigned to

strong-medium and Asymmetric C=C=C Stretching Vibration.

A band pointed at 1163.09 cm^{-1} is assigned to strong O-H deformation and C-O Stretching Vibrationc interaction. The band observed at 710.77 cm^{-1} is assigned to strong N-H Deformation Vibration. The band at 1013.12 cm^{-1} is assigned to strong C-O Stretching Vibration. A band observed at 542.48 cm^{-1} is assigned to strong C-C-C Stretching vibration.

Thickness measurement using Air Wedge method

The air wedge glass plates and the thin film samples, sodium vapour lamp and stand were used in this experiment. Using air wedge microscope the thickness of the samples is measured and tabulated in below.

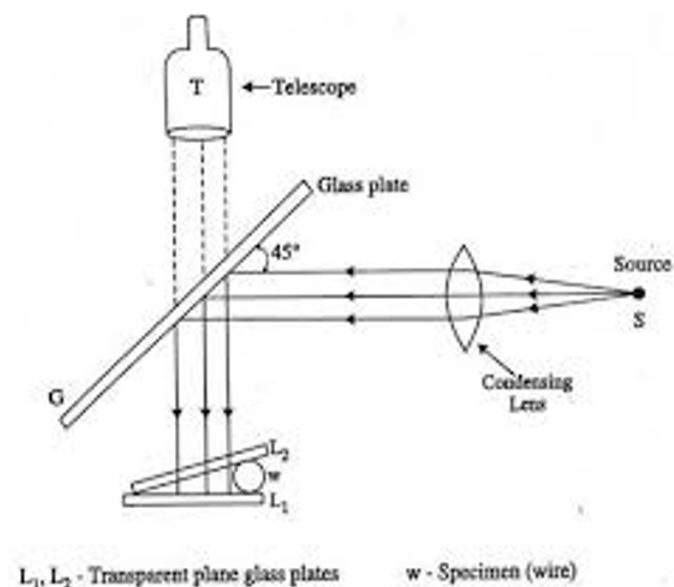


Figure 3: Air wedge method using measure the thickness of Mn. CdO thin films

It consisted of a sodium vapour lamp set, air wedge microscope and 45° turning glass plate. Using this air wedge setup, thickness of pure CdO and Manganese doped CdO thin films were studied.

The thickness of thin films seemed to increases with Manganese doping percentage 0.1%.

Thin film materials	Thickness (nm) $\times 10^{-3}$
Pure CdO	1.2504
Mn.CdO	6.866

It is observed that the thickness of the Mn doped CdO is higher than pure CdO.

REFERENCES

1. A Goswami, Thin film fundamentals, New Age International (P) limited Publishers, 1996, New Delhi.
2. N.Manjula, M.Pugalethi, "Effect of doping concentration on the structural, morphological, optical and electrical properties of Mn doped CdO thin films", materials science poland,2015 Vol.33 no.4 pages 774-781.

3. Zayed A. Alahmed, "Optical band gap controlling of nanostructure Mn doped CdO thin films prepared by sol-gel spin coating material", International journals for light and electron optics.
4. K.Sankarasubramaniand, "Influence of Mn doping on structural, optical and electrical properties of CdO thin films prepared by cost effective spray pyrolysis method science", semiconductor processing26(1)method".
5. y.abdollahi, A.H. Abdullah,1,2, "Synthesis and characterization of Mn doped zno nanoparticle" International journals of Basic&Applied science IJBAS-IJENS, Vol:11 No:04.

EXAMPLE REFERENCES

1. A Goswami, Thin film fundamentals, New Age International (P) limited Publishers, 1996, New Delhi.
2. Zayed A. Alahmed, "Optical band gap controlling of nanostructure Mn doped CdO thin films prepared by sol-gel spin coating material", International journals for light and electron optics.